AMENDMENTS TO THE CLAIMS

In accordance with 37 C.F.R. §1.121(c), please amend the claims as indicated in

marked-up form below, where additions are underlined, deletions are struck through, and

new claims are presented without markings.

1. (Currently Amended) A microelectronic device comprising:

a package substrate having a first side and an opposing second side;

a package connector at the second side of the package substrate and a board

coupled to the package connector;

a microprocessor adjacent to the first side of the package substrate; and

a memory device adjacent to the second side of the package substrate, wherein the

package substrate is electrically coupled to at least one of the microprocessor and the

memory device and wherein the memory device is located in a cavity defined by the

package connector, the package substrate, and the board.

2. (Original) The apparatus of Claim 1, further comprising a memory controller

electrically coupled to the memory device.

3. (Original) The apparatus of Claim 1, further comprising a thin film capacitor

integral to the substrate.

4. (Currently Amended) The apparatus of Claim 1, the second die memory device

disposed on a land side of the package substrate.

5. (Original) The apparatus of Claim 1, further comprising a third die including a

second microprocessor, a fourth die including a third microprocessor, and a fifth die

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including a fourth microprocessor.

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6. (Currently Amended) The apparatus of Claim 5, the second die memory device

electrically coupled by one selected from the group including a wirebond electrical

interconnect, a flip-chip ball grid array electrical interconnect, a lead frame interconnect,

and a combination thereof.

7. (Original) The apparatus of claim 1 further comprising a die including one

selected from the group including a memory device, a memory controller, an application

specific integrated circuit (ASIC), a graphics processor, a signal processor, a radio

transceiver, and a combination thereof.

8. (Original) The memory device of Claim 7 further comprising a fourth level

cache.

9. (Currently Amended) The apparatus of Claim 1, the package further including an

integrated heat spreader thermally coupled to one or more of the die microprocessor and

the memory device.

10-17. (Canceled)

18. (Withdrawn) A system comprising:

a package including an integrated circuit disposed on two or more electrically

coupled die, the first die including a microprocessor and the second die including a

memory device;

a system memory bus coupled to the microprocessor;

a package substrate electrically coupled to at least one of the die; and

a mass storage device coupled to the package, wherein the memory device has a

speed that exceeds a speed of the system memory bus.

19. (Withdrawn) The system of Claim 18 wherein the memory device further

comprises a fourth level cache.

20. (Withdrawn) The system of claim 18, further comprising:

a dynamic random access memory coupled to the integrated circuit; and

an input/output interface coupled to the integrated circuit.

21. (Withdrawn) The system of claim 20, wherein the input/output interface

comprises a networking interface.

22. (Withdrawn) The system of claim 18, wherein the system is a selected one of a

group comprising a set-top box, a media-center personal computer, a digital versatile disk

player, a server, a personal computer, a mobile personal computer, a network router, and

a network switching device.

23. (Withdrawn) The system of claim 18, the memory device disposed in a recess

formed by a land grid array socket, the package electrically coupled to the land grid array

connector.

24. (Withdrawn) The system of claim 23, the land grid array connector coupled to a

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printed circuit board assembly capable of further coupling to a motherboard.

25. (Previously Presented) The microelectronic device of claim 8, wherein the

fourth level cache has a capacity ranging between approximately 500 megabytes and

approximately 1 gigabyte.

26. (Previously Presented) The microelectronic device of claim 25 further

comprising a system memory bus coupled to the microprocessor, wherein the fourth level

cache has a speed greater than a speed of the system memory bus.

27. (Currently Amended) The microelectronic device of claim 1 further comprising

wherein the package connector comprises a land grid array connector coupled to the

package substrate.

28. (Currently Amended) The microelectronic device of claim 1 further comprising

wherein the package connector comprises a pin grid array connector coupled to the

package substrate.

29. (Currently Amended) A microelectronic device comprising:

a package substrate;

a package\_connector\_coupled\_to\_the\_package\_substrate\_and\_a\_board\_coupled\_to\_the

package connector;

a microprocessor coupled to the package substrate; and

a memory device coupled to the package substrate, wherein the memory device

comprises a fourth level cache and wherein the memory device is located in a cavity

defined by the package connector, the package substrate, and the board.

30. (Previously Presented) The microelectronic device of claim 29 wherein:

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the fourth level cache has a capacity ranging between approximately 500

megabytes and approximately 1 gigabyte.

31. (Previously Presented) The microelectronic device of claim 30 further

comprising:

a third level cache and a system memory bus,

wherein:

the fourth level cache has a speed greater than a speed of the system

memory bus; and

the capacity of the fourth level cache is greater than a capacity of the third

level cache.

32. (Currently Amended) The microelectronic device of claim 31 further

comprising wherein the package connector is one of a land grid array connector and a pin

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grid array connector <del>coupled to the package substrate</del>.

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